

# Structure of CoO(001) surface from DFT+U calculations

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# Motivation

- Transition-metal oxides(TMOs) exhibit outstanding photo-catalytic activities which are generally surface-dependent.
- basic DFT calculations :
  - 1 insulating behaviour : NiO
  - 2 metallic or semi-metallic behaviour: CoO
- lattice distortions might induce :
  - symmetry breaking
  - unquenched orbital magnetic moment.
- existence of a multideterminant ground state ?
- interaction between electrons of the unfilled 3d shell
- DFT+U method
- CoO(001) surface

# Summary

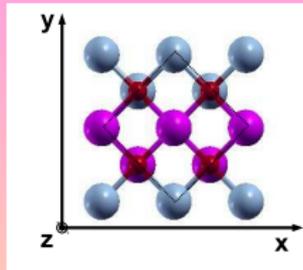
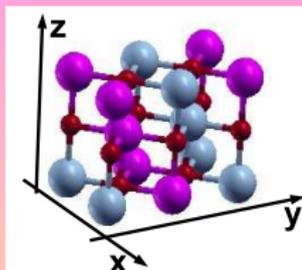
- Introduction
- calculation of the Hubbard parameter  $U$  for CoO
- CoO bulk and surface relaxation
- Multiple-Quantum well behavior



## Theoretical details

- Generalized Gradient Approximation-Perdew Burke Ernzerhof(GGA-PBE)
- Ultrasoft pseudopotentials with Rappe Rabe Kaxiras Joannopoulos(RRKJ)
- 9 valence electrons for Cobalt and 6 for Oxygen atoms.
- 40 Ry cutoff for energy
- 320 Ry cutoff for density
- Monkhorst-Pack k-points for integrations
- $12 \times 12 \times 12$  for bulk calculations,
- $12 \times 6 \times 1$  for  $1 \times 2$  on xy plane slabs
- $6 \times 6 \times 1$  for  $2 \times 2$  slabs

## Slabs used in the calculation



$1 \times 2$  three layers slab . Top view of a  $2 \times 2$  slab.

- CoO(001) is experimentally a non polar surface.
- vacuum of  $17.06 \text{ \AA}$  in the direction perpendicular to the surface.
- no need to apply a dipole correction
- Quantum ESPRESSO suite of codes on K20 GPU

## Computation of U

- M. Cococcioni and S. de Gironcoli, Phys. Rev. B 71, 035105 (2005)

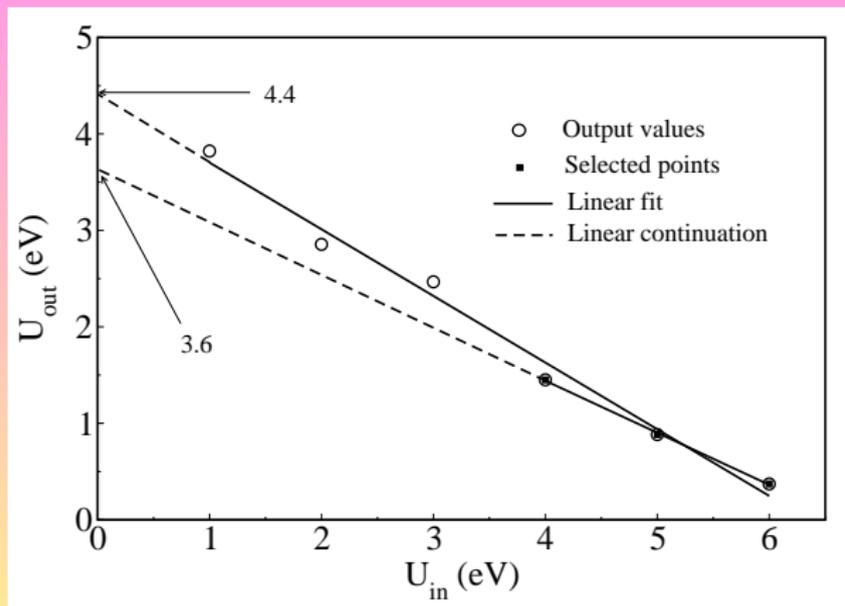
$$U = \frac{\partial \alpha_I^{KS}}{\partial n_I} - \frac{\partial \alpha_I}{\partial n_I} = (\chi_0^{-1} - \chi^{-1})_{II}. \quad (1)$$

- $\alpha$  : perturbation imposed on site atom  $I$
  - $n_I$  : occupations numbers
  - $\chi$  : response matrices
- H. J. Kulik, M. Cococcioni, D. A. Scherlis, and N. Marzari, Phys. Rev. Lett. 97, 103001 (2006)
    - converged value of U by a linear fit
    - $U_0$  for one unit cell of 4 atoms, zero Hubbard potential.
    - $U_{in}$  is provided  $U_{out}$  can be computed from linear response.

$$U_{out} = U_{scf} - \frac{U_{in}}{m} \quad (2)$$

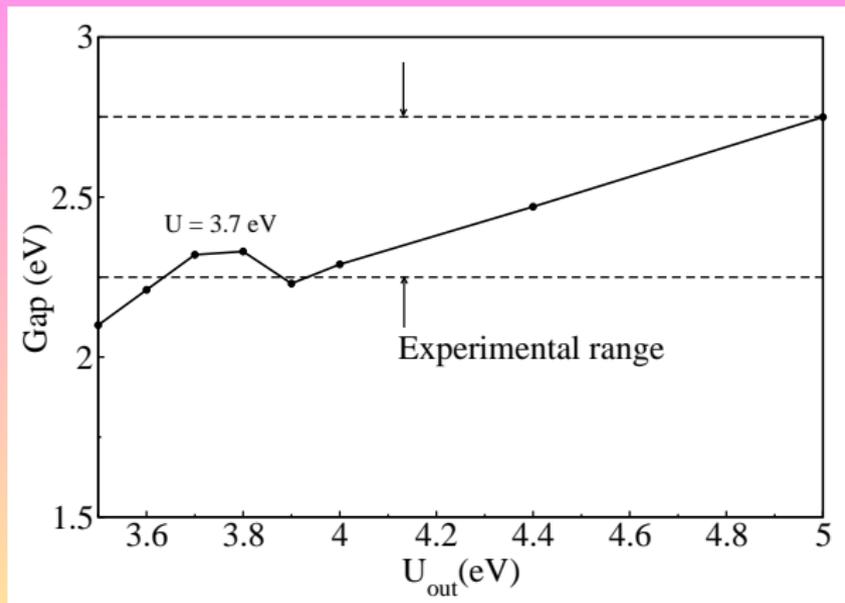
- $m$  is a degeneracy parameter

# Computation of U



- $U=3.7$  eV gives a gap of 2.3 eV

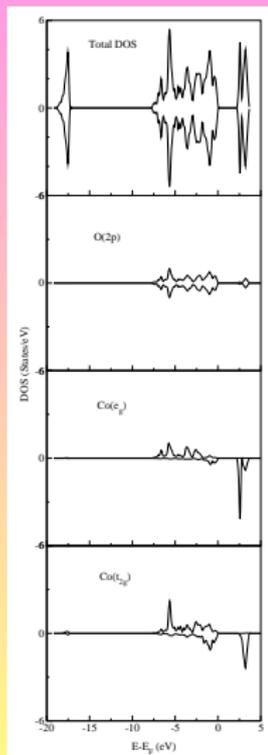
## Band gap



CoO band gap as a function of  $U$  around  $U_{scf}$ .

- exact ground state.
- Meredig et al. failed to locate the ground state
- they used the value  $U_{eff} = 6.1$  eV previously reported for CoO

## DOS



- doubled peak in the conduction band from unoccupied  $t_{2g}$  and  $e_g$  states.
- weak separation between the two states :  $\text{Co}^{2+}$  is in a weak field or high spin configuration.
- top of the valence band is mainly dominated by oxygen p states
- bottom of the conduction band has its major contribution from  $t_{2g}$  state.
- CoO is a charge transfer insulator instead of Mott-Hubbard kind.

## Magnetic moment

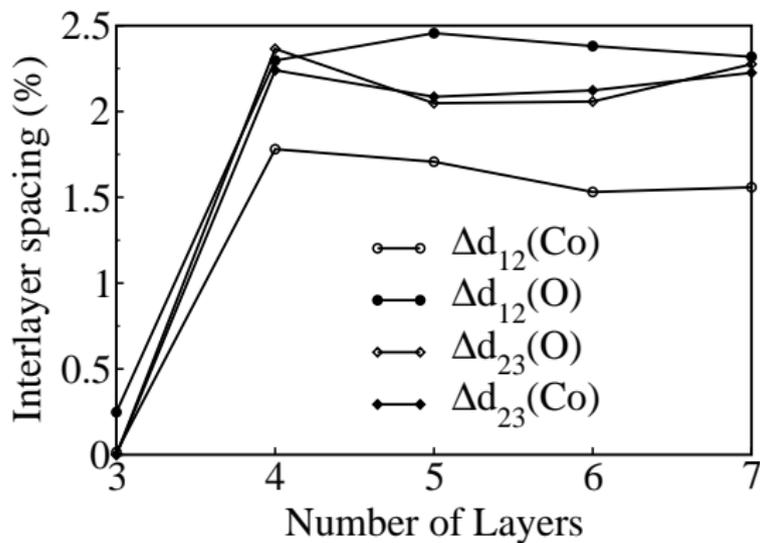
- $\text{Co}^{2+}$  ions :  $2.9\mu_B$ .
- Rödl et al. in 2009 reported GGA and GGA+U total spin moment of  $2.4\text{-}2.6\mu_B$ ,
- $\text{Co}^{2+}$  magnetic moment ( $\mu_B$ ) in CoO. Orbital contribution is about  $0.8\mu_B$

Magnetic moment	Method	Component
$3.8\pm 0.1$ Herrmann et al. 1978	exp.	total
3.98(6) Jauch et al. 2001	exp.	total
2.80-2.84 Imada et al. 2001	exp.	spin component only
2.74 Wdowik et al. 2007	GGA+U	spin component only
2.90 This work	GGA+U	spin component only

## CoO surface

- bulk NiO has similar properties than CoO
- (001) surfaces STM images are different.
- CoO(001) appears to exhibit a small rumpling.
- At topmost surface layer, the relaxation height of Co ions is different from O ions
- Surface relaxation of O ions is almost 2.3%
- Cobalt ions  $\Delta d_{12} = 1.5\%$ .
- $\Delta d_{23} = 2.1\%$  from the second surface layer.
- Relaxations are outwards : exp. results from Felton et al . 1979
- Surface atoms in CoO relax by less than  $\pm 3\%$  with respect to bulk spacing.

# CoO surface structure



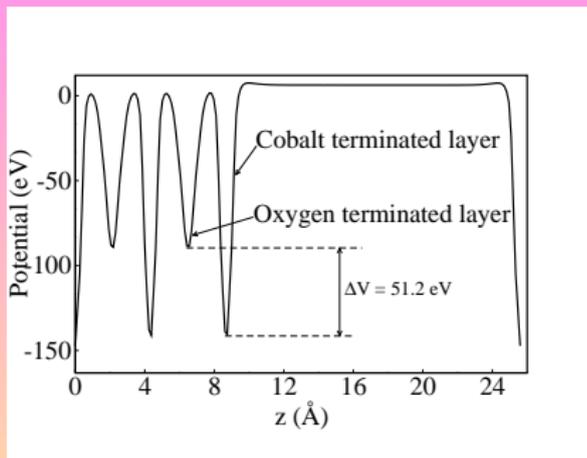
## Surface energy

- Surface energy was calculated according to

$$\sigma = \frac{1}{2A}(E_{slab} - nE_{bulk}) \quad (3)$$

- $E_{slab}$  total energy of the relaxed slabs
- $E_{bulk}$  the optimized bulk energy per formula unit
- $n$  the number of formula units in a slab
- $2A$  the total area of the surface.
- Surface energy of CoO(001) of  $0.8J/m^2$ .
- Low surface energy indicates CoO(001) surface is energetically very favorable for catalytic applications.

## Quantum well



- Multiple Quantum Wells (MQWs)
- Difference between O-terminated and the Co-terminated
- Potential difference  $\Delta V = 51.2 \text{ eV}$  is somewhat high.
- CoO surface could be useful for optoelectronic devices

## Conclusion

- Two effective Hubbard parameters  $U$ : 7.1 eV and 3.7 eV could be used.
- Self consistency determination ?
- Property under investigation ?
- We argued that the value  $U=3.7$  eV is the most suitable.
- CoO(001) surface atoms relax outwards
- Rumpling from discrepancy between O ions and Co ions relaxation
- Band gap and surface energy : CoO(001) is favorable for catalysis
- Optoelectronic applications based on Multiple Quantum Well devices
- Perspectives : study other TM oxides and more complicated systems
- Model catalytic effects
- Thanks : ANR MINAFRC, Souad Ammar-Merah